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## N-Channel JFETs

### PRODUCT SUMMARY

Part Number	$V_{GS(off)}$ (V)	$V_{(BR)GSS}$ Min (V)	$g_{fs}$ Min (mS)	$I_{DSS}$ Min (mA)
2N4416	$- \leq 6$	-30	4.5	5
2N4416A	-2.5 to -6	-35	4.5	5
SST4416	$- \leq 6$	-30	4.5	5

### FEATURES

- Excellent High-Frequency Gain: 2N4416/A, Gps 13 dB (typ) @ 400 MHz
- Very Low Noise: 3 dB (typ) @ 400 MHz
- Very Low Distortion
- High AC/DC Switch Off-Isolation

### BENEFITS

- Wideband High Gain
- Very High System Sensitivity
- High Quality of Amplification
- High-Speed Switching Capability
- High Low-Level Signal Amplification

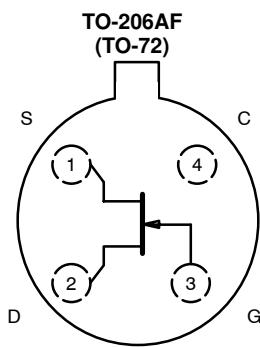
### APPLICATIONS

- High-Frequency Amplifier/Mixer
- Oscillator
- Sample-and-Hold
- Very Low Capacitance Switches

### DESCRIPTION

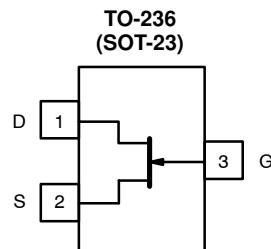
The 2N4416/2N4416A/SST4416 n-channel JFETs are designed to provide high-performance amplification at high frequencies.

The TO-206AF (TO-72) hermetically-sealed package is available with full military processing (see Military Information.) The TO-236 (SOT-23) package provides a low-cost option and is available with tape-and-reel options (see Packaging Information). For similar products in the TO-226AA (TO-92) package, see the J304/305 data sheet.



Top View

2N4416  
2N4416A



Top View

SST4416 (H1)\*

\*Marking Code for TO-236

For applications information see AN104.

**ABSOLUTE MAXIMUM RATINGS**

Gate-Drain, Gate-Source Voltage :											
(2N/SST4416) .....	-30 V										
(2N4416A) .....	-35 V										
Gate Current .....	10 mA										
Lead Temperature .....	300 °C										
Storage Temperature :	(2N Prefix) .....	-65 to 200 °C									
	(SST Prefix) .....	-65 to 150 °C									
Operating Junction Temperature .....		-55 to 150 °C									
Power Dissipation :	(2N Prefix) <sup>a</sup> .....	300 mW									
	(SST Prefix) <sup>b</sup> .....	350 mW									

## Notes

- a. Derate 2.4 mW/°C above 25°C
- b. Derate 2.8 mW/°C above 25°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**SPECIFICATIONS ( $T_A = 25^\circ\text{C}$  UNLESS NOTED)**

Parameter	Symbol	Test Conditions	Typ <sup>a</sup>	Limits						Unit	
				2N4416		2N4416A		SST4416			
				Min	Max	Min	Max	Min	Max		
<b>Static</b>											
Gate-Source Breakdown Voltage	$V_{(\text{BR})\text{GSS}}$	$I_G = -1 \mu\text{A}, V_{DS} = 0 \text{ V}$	-36	-30		-35		-30		V	
Gate-Source Cutoff Voltage	$V_{GS(\text{off})}$	$V_{DS} = 15 \text{ V}, I_D = 1 \text{ nA}$	-3		-6	-2.5	-6		-6		
Saturation Drain Current <sup>b</sup>	$I_{DSS}$	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}$	10	5	15	5	15	5	15	mA	
Gate Reverse Current	$I_{GSS}$	$V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$ (2N)	-2		-100		-100			pA	
		$T_A = 150^\circ\text{C}$	-4		-100		-100			nA	
		$V_{GS} = -15 \text{ V}, V_{DS} = 0 \text{ V}$ (SST)	-0.002						-1		
		$T_A = 125^\circ\text{C}$	-0.6								
Gate Operating Current	$I_G$	$V_{DG} = 10 \text{ V}, I_D = 1 \text{ mA}$	-20							pA	
Drain Cutoff Current <sup>c</sup>	$I_{D(\text{off})}$	$V_{DS} = 10 \text{ V}, V_{GS} = -6 \text{ V}$	2								
Drain-Source On-Resistance <sup>c</sup>	$r_{DS(\text{on})}$	$V_{GS} = 0 \text{ V}, I_D = 300 \mu\text{A}$	150							Ω	
Gate-Source Forward Voltage <sup>c</sup>	$V_{GS(F)}$	$I_G = 1 \text{ mA}, V_{DS} = 0 \text{ V}$	0.7							V	
<b>Dynamic</b>											
Common-Source Forward Transconductance <sup>b</sup>	$g_{fs}$	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}$ $f = 1 \text{ kHz}$	6	4.5	7.5	4.5	7.5	4.5	7.5	mS	
Common-Source Output Conductance <sup>b</sup>	$g_{os}$		15		50		50		50	μS	
Common-Source Input Capacitance	$C_{iss}$	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}$ $f = 1 \text{ MHz}$	2.2		4		4			pF	
Common-Source Reverse Transfer Capacitance	$C_{rss}$		0.7		0.8		0.8				
Common-Source Output Capacitance	$C_{oss}$		1		2		2				
Equivalent Input Noise Voltage <sup>c</sup>	$\bar{e}_n$	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}$ $f = 1 \text{ kHz}$	6							nV/ √Hz	

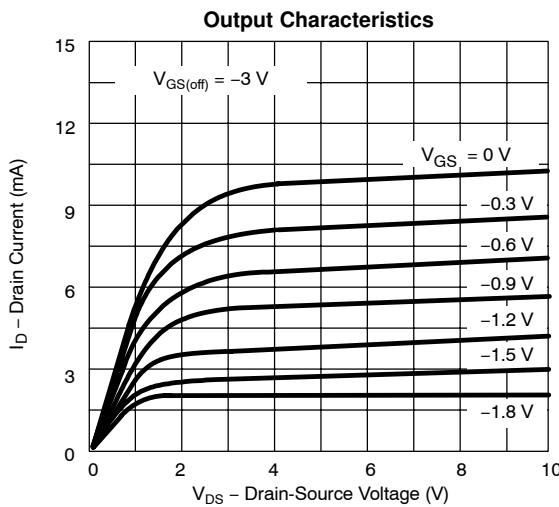
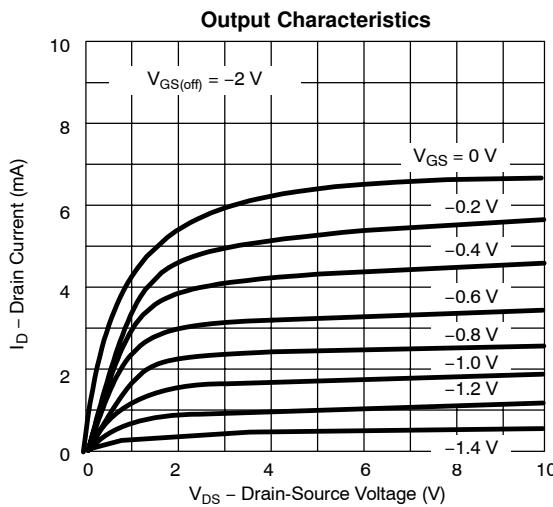
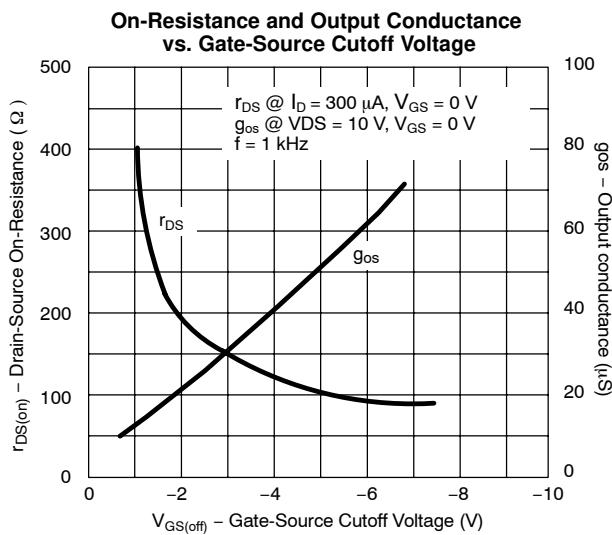
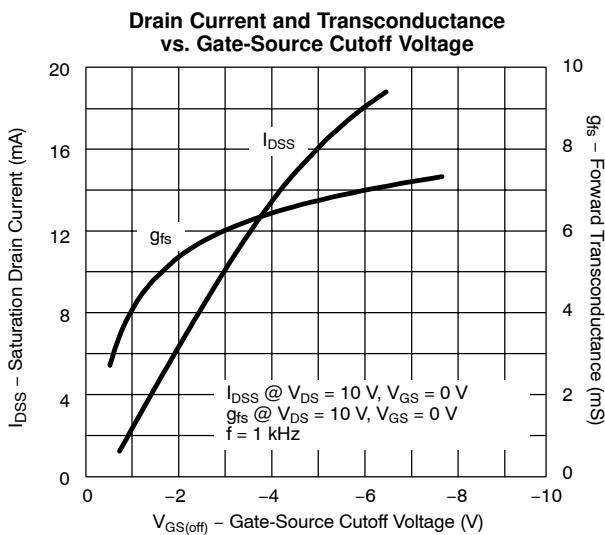
**HIGH-FREQUENCY SPECIFICATIONS FOR 2N4416/2N4416A ( $T_A = 25^\circ\text{C}$  UNLESS NOTED)**

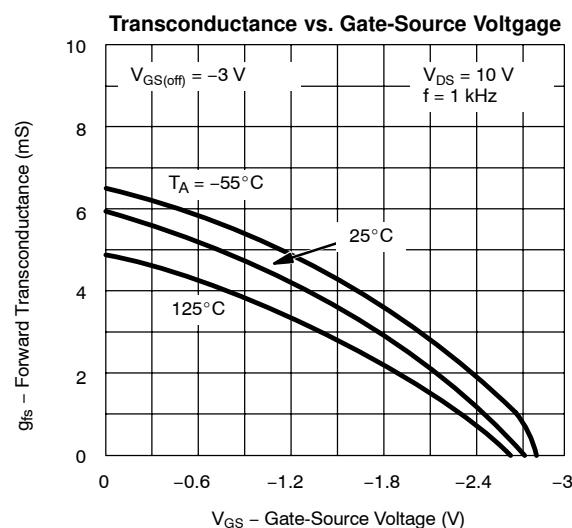
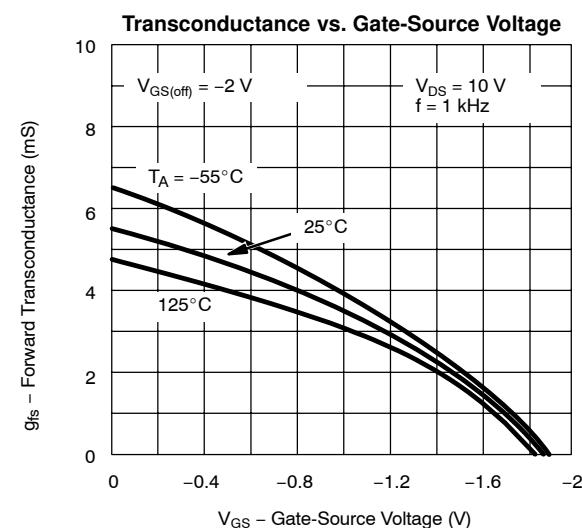
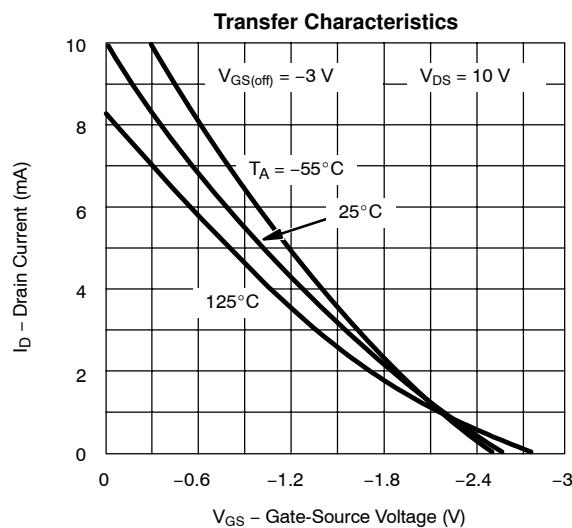
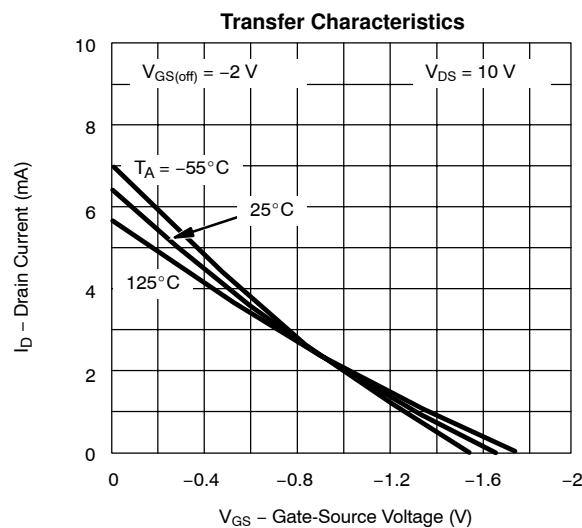
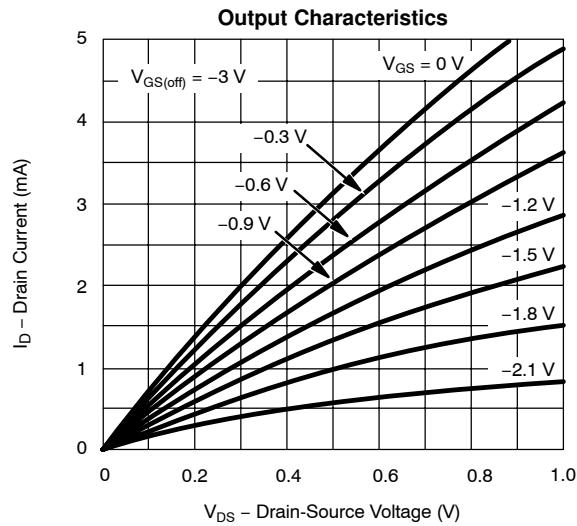
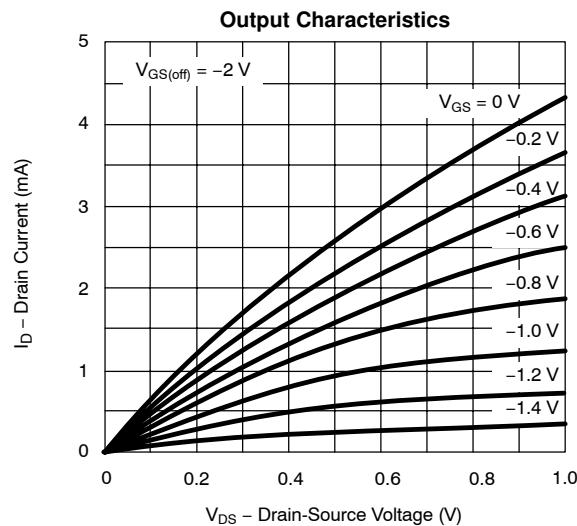
Parameter	Symbol	Test Conditions	Limits				Unit	
			100 MHz		400 MHz			
			Min	Max	Min	Max		
Common Source Input Conductance <sup>d</sup>	$g_{iss}$	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}$		100		1,000	$\mu\text{s}$	
Common Source Input Susceptance <sup>d</sup>	$b_{iss}$			2,500		10,000		
Common Source Output Conductance <sup>d</sup>	$g_{oss}$			75		100		
Common Source Output Susceptance <sup>d</sup>	$b_{oss}$			1,000		4,000	$\text{dB}$	
Common Source Forward Transconductance <sup>d</sup>	$g_{fs}$					4,000		
Common-Source Power Gain <sup>d</sup>	$G_{ps}$		18		10			
Noise Figure <sup>d</sup>	NF	$V_{DS} = 15 \text{ V}, I_D = 5 \text{ mA}$		$R_G = 1 \text{ k}\Omega$	2		4	

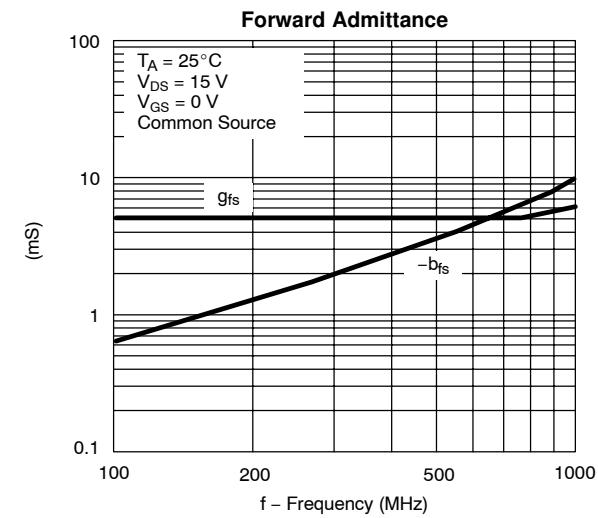
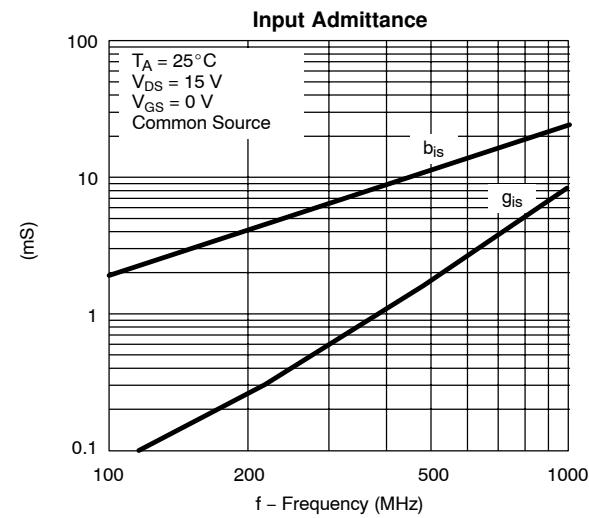
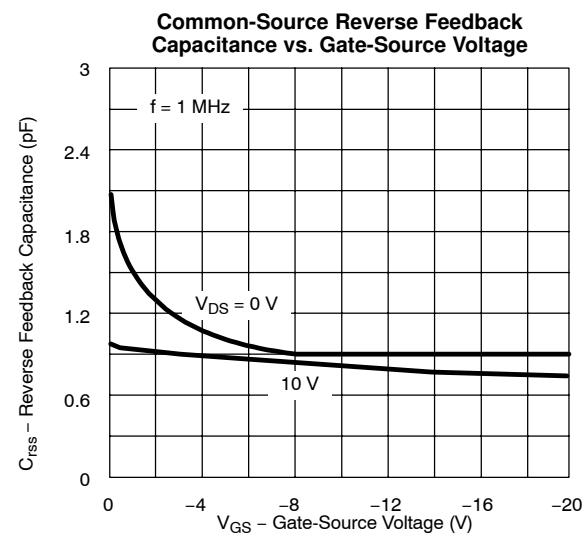
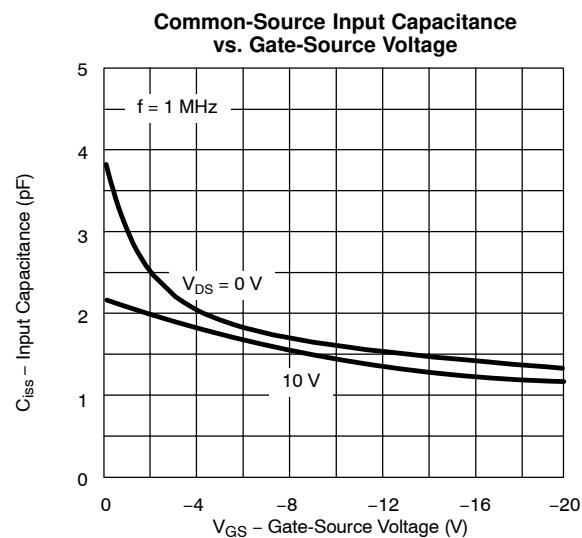
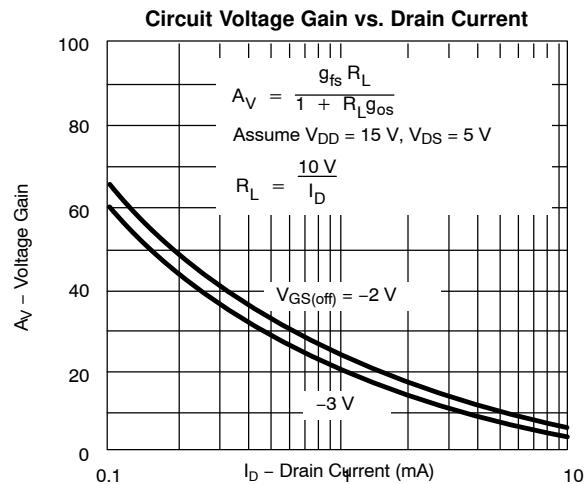
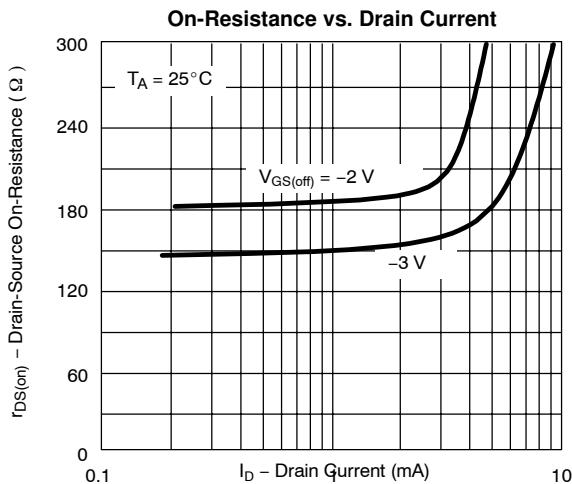
Notes

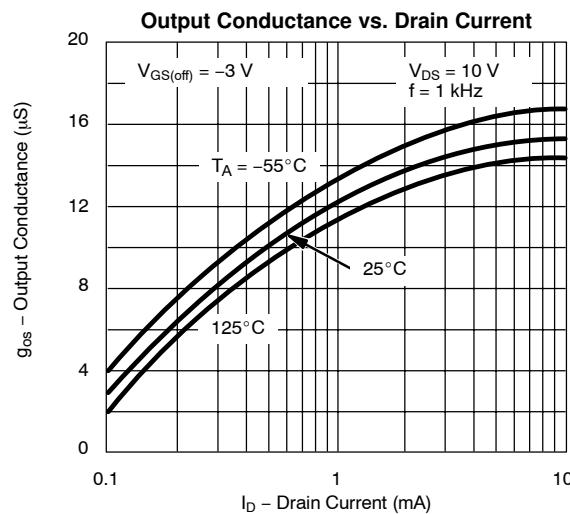
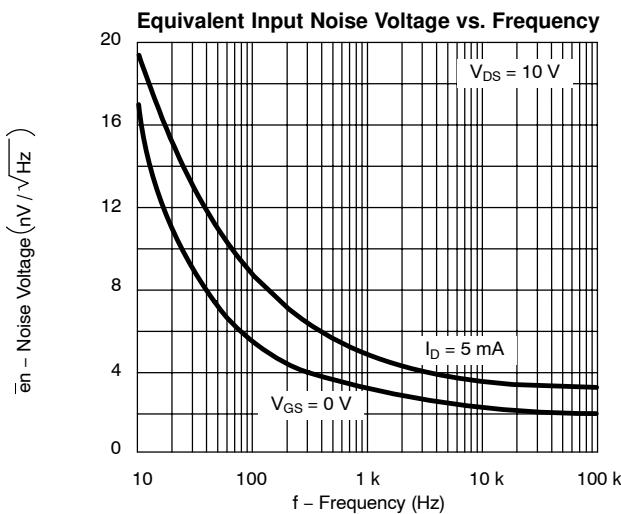
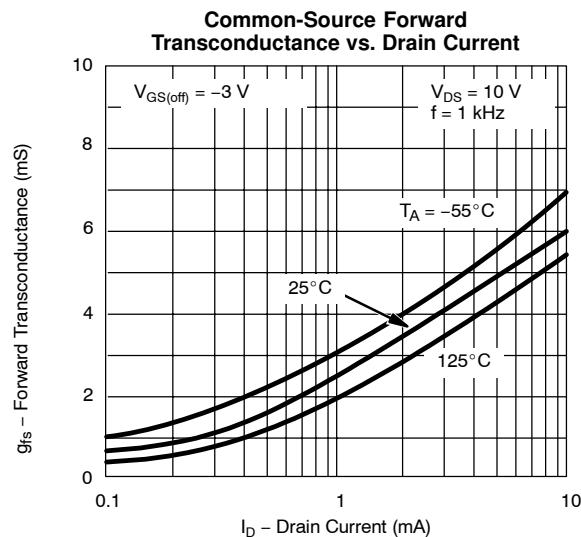
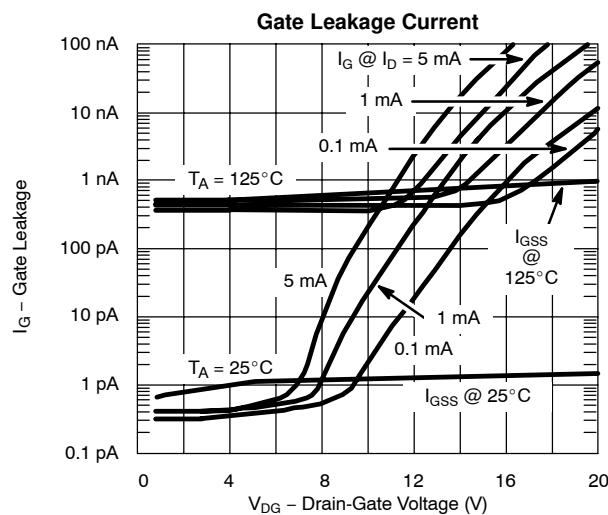
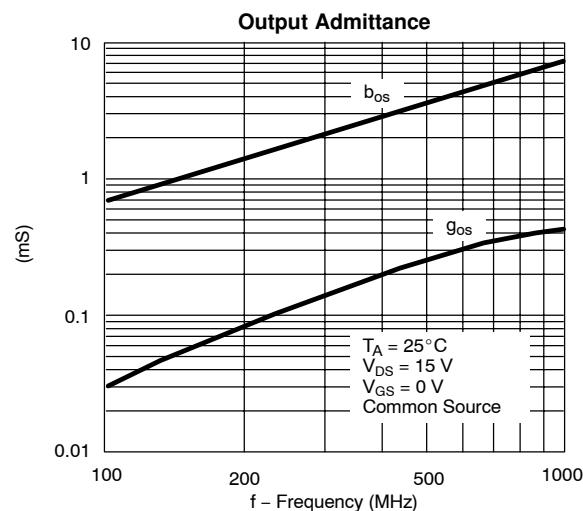
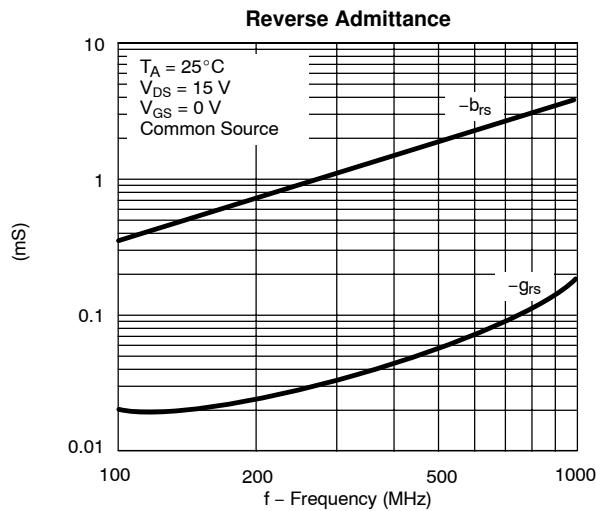
- a. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- b. Pulse test: PW  $\leq 300 \mu\text{s}$  duty cycle  $\leq 3\%$ .
- c. This parameter not registered with JEDEC.
- d. Not a production test.

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**TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED)**


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